

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of :
Masahiko SANO et al. :
Serial No. NEW : Attn: APPLICATION BRANCH
Filed July 9, 2003 : Attorney Docket No. 2003_0889

A NITRIDE SEMICONDUCTOR ELEMENT
WITH A SUPPORTING SUBSTRATE AND
A METHOD FOR PRODUCING A NITRIDE
SEMICONDUCTOR ELEMENT
(Rule 1.53(b) Divisional
of Serial No. 10/351,497,
Filed January 27, 2003)

THE COMMISSIONER IS AUTHORIZED
TO CHARGE ANY DEFICIENCY IN THE
FEES FOR THIS PAPER TO DEPOSIT
ACCOUNT NO. 23-0975

PRELIMINARY AMENDMENT

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

Prior to initial examination of the above-identified application, kindly amend the application as follows: